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Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V _{CBO}	-60	
Collector - Emitter Voltage	V _{CEO}	-50	V
Emitter - Base Voltage	V _{EB0}	-6	
Collector Current - Continuous	I _c	150	mA
Collector Power Dissipation	P _c	200	mW
Junction Temperature	T _J	150	
Storage Temperature range	T _{stg}	-55 to 150	#

Typical Characteristics

